

Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a TO263 (D2PAK) surface mountable plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This "series B" triac will commutate the full rated RMS current at the maximum rated junction temperature without the aid of a snubber.

2. Features and benefits

- 3Q technology for improved noise immunity
- High blocking voltage capability
- · High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- · Less sensitive gate for very high noise immunity
- · Planar passivated for voltage ruggedness and reliability
- Surface mountable package
- Triggering in three quadrants only

3. Applications

- Heating controls
- High power motor control
- High power switching

4. Quick reference data

Table 1. Q	uick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	600	V
$I_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	full sine wave; T _{mb} ≤ 91 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	25	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	190	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	-	209	А
Tj	junction temperature		-	-	125	°C
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	2	18	50	mA
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3Q Hi-Com Triac

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	2	21	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 7	2	34	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	31	60	mA
V _T	on-state voltage	I _T = 30 A; T _j = 25 °C; <u>Fig. 10</u>	-	1,3	1.55	V
Dynamic	characteristics	·				
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; \text{ T}_{\text{j}} = 125 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit	1000	4000	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_{\text{D}} = 400 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; \text{I}_{\text{T(RMS)}} = 25 \text{ A}; \\ \text{dV}_{\text{com}}/\text{dt} = 20 \text{ V}/\mu\text{s}; \text{ gate open circuit}; \\ \underline{\text{Fig. 12}}$	-	44	-	A/ms

5. Pinning information

Table 2. P	Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol					
1	T1	main terminal 1							
2	T2	main terminal 2		T2-T1					
3	G	gate		G sym051					
mb	T2	mounting base; main terminal 2		synus i					

6. Ordering information

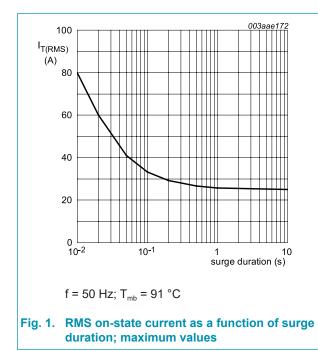
Table 3. Ordering information									
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date			
BTA225B-600B	TO263	BTA225B-600B,118	Reel	800	TO263E	26-May-2017			

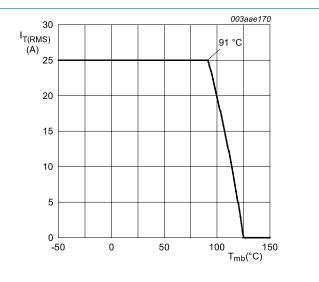
7. Limiting values

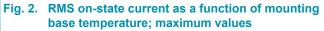
Table 4. Limiting values

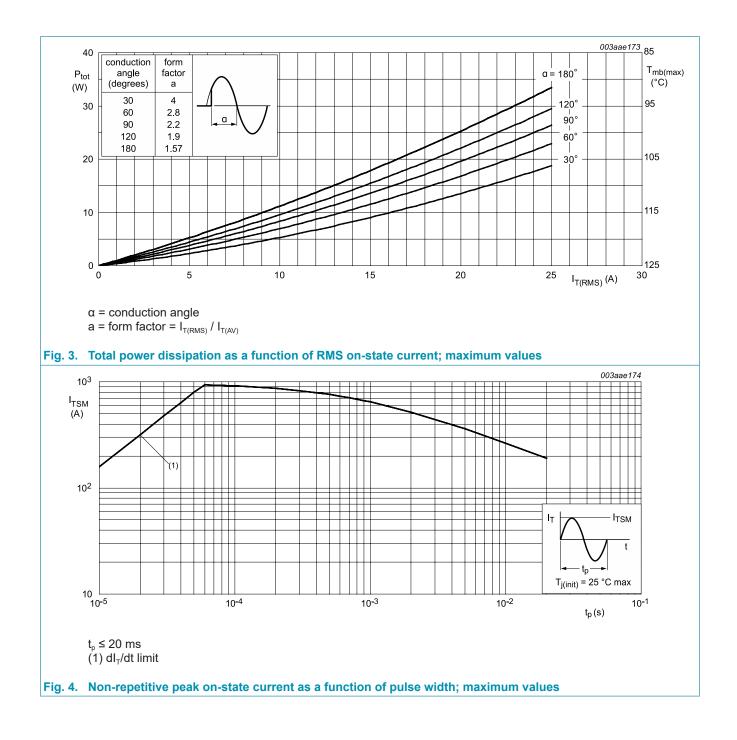
In accordance with the Absolute Maximum Rating System (IEC 60134).

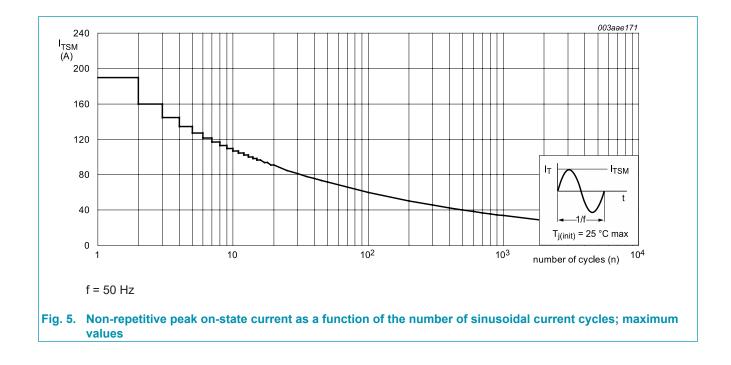
Symbol	Parameter	Conditions	Min	Max	Unit
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I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 91 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	25	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5	-	190	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	209	А
l ² t	l ² t for fusing	t _P = 10 ms; SIN	-	180	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 100 mA	-	100	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
T _j	junction temperature		-	125	°C





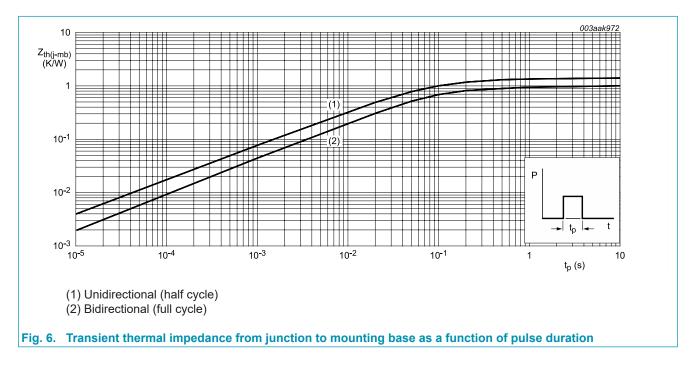






8. Thermal characteristics

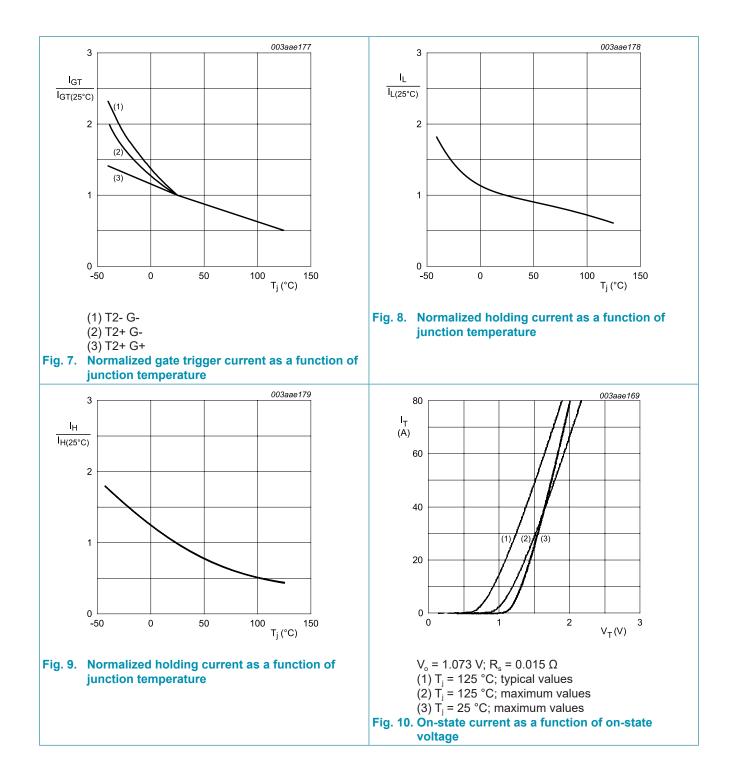
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance	full cycle; <u>Fig. 6</u>	-	-	1	K/W
	from junction to mounting base	half cycle; <u>Fig. 6</u>	-	-	1.4	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	printed circuit board (FR4) mounted	-	55	-	K/W



9. Characteristics

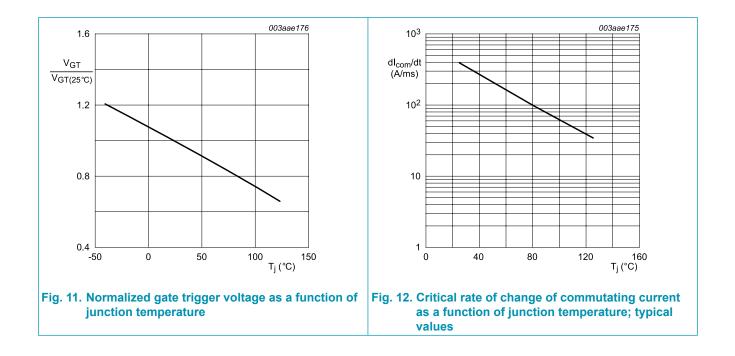
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 7}$	2	18	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 7</u>	2	21	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 7</u>	2	34	50	mA
l	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 8}$	-	31	60	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 8</u>	-	34	90	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	30	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	31	60	mA
V _T	on-state voltage	I _T = 30 A; T _j = 25 °C; <u>Fig. 10</u>	-	1,3	1.55	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; <u>Fig. 11</u>	0.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit	1000	4000	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 25 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu s;$ gate open circuit; Fig. 12	-	44	-	A/ms

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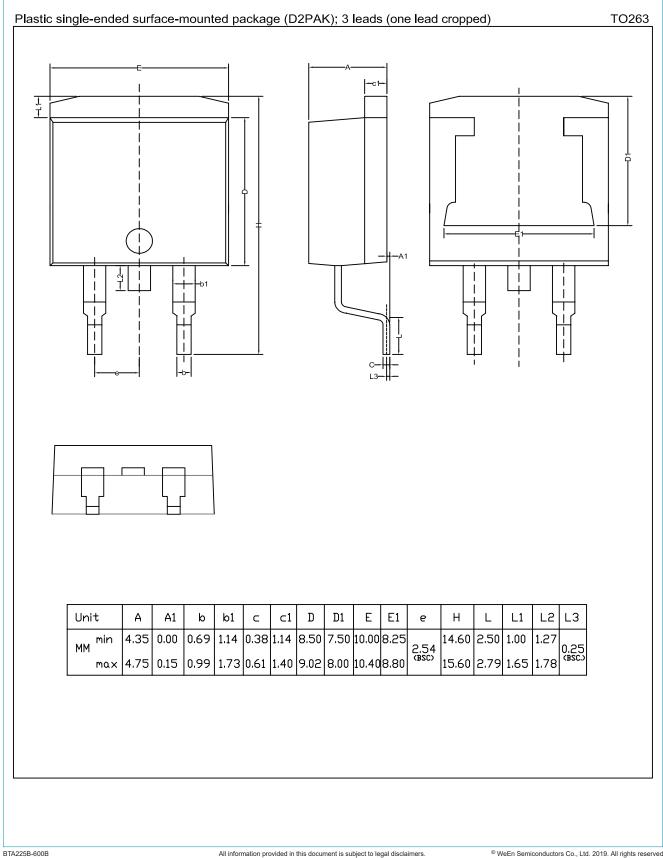


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BTA225B-600B



10. Package outline



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11. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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